Process optimization of Joule heating CVD of graphene on meter-scale copper foil

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Abstract

Chemical vapor deposition (CVD) is currently the most promising method for producing large-area, high-quality graphene films [1]. Roll-to-roll CVD synthesis has been attempted to minimize the time in heating and cooling the CVD chamber [2-4]. A Joule heating-based synthesis method that uses high current flows through a copper foil and resistively heats the foil up to a prescribed temperature, has the advantage of low power consumption and small thermal mass [4]. However, this method has not been extensively researched due to difficulties in achieving uniform temperature distribution across the copper foil. To address this issue, we propose a U-shaped copper foil configuration that enhances temperature uniformity. The experimental design method was used to establish the optimal graphene synthesis conditions, and graphene was continuously synthesized while transporting a 2-meter-long copper foil. Electron microscopy and sheet resistance measurement confirmed the high-quality of the synthesized graphene.

References

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Figures



Figure 1: Schematic of Joule heating-based roll-to-roll graphene synthesis equipment



Figure 2: Raman spectra and SEM image of graphene/Cu foil